NSN 5962-01-364-1996

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Programmed
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Bipolar metal-oxide semiconductor
Case Outline Source And Designator:
D-2 mil-m-38510
Terminal Surface Treatment:
Solder
Product Name:
Bipolar prom
Voltage Rating And Type Per Characteristic:
5.5 volts absolute input and 7.0 volts absolute input
Memory Device Type:
Prom
Test Data Document:
49956-979735-104 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,
etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
16 printed circuit
Specification Data:
96906-mil-std-883/tx/ government standard
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
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